

PolarHV[™] HiPerFET IXFC 16N80P Power MOSFET ISOPLUS220[™]

(Electrically Isolated Back Surface)

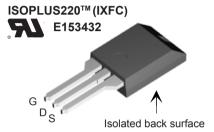
N-Channel Enhancement Mode Fast Intrinsic Diode Avalanche Rated



$V_{\scriptscriptstyle \sf DSS}$	=	800	V
I _{D25}	=	9	Α
R _{DS(on)}	≤	650	$m\Omega$
t _{rr}	≤	250	ns

Symbol	Test Conditions	Maximum R	Maximum Ratings		
V _{DSS} V _{DGR}	$T_J = 25^{\circ} \text{ C to } 150^{\circ} \text{ C}$ $T_J = 25^{\circ} \text{ C to } 150^{\circ} \text{ C}; R_{GS} = 1 \text{ M}\Omega$	800 800	V		
V _{GS} V _{GSM}	Continuous Transient	± 30 ±40	V		
 _{D25} _{DM}	$T_{\rm c}$ = 25° C $T_{\rm c}$ = 25° C, pulse width limited by $T_{\rm JM}$	9 48	A A		
I _{AR} E _{AR} E _{AS}	T _C = 25° C T _C = 25° C T _C = 25° C	8 30 1.5	A mJ J		
dv/dt	$I_{S} \leq I_{DM}, \text{ di/dt} \leq 100 \text{ A/}\mu\text{s}, V_{DD} \leq V_{DSS},$ $T_{J} \leq 150^{\circ}\text{ C}, R_{G} = 5 \Omega$	10	V/ns		
P_{D}	T _C = 25° C	150	W		
T _J T _{JM} T _{stg}		-55 +150 150 -55 +150	°C °C °C		
T _L T _{SOLD} V _{ISOL}	1.6 mm (0.062 in.) from case for 10 s Plastic body for 10 s 50/60 Hz, RMS, t = 1, leads-to-tab	300 260 2500	°C °C V~		
F _C	Mounting Force	1165/2.515	N/lb		
Weight		2	9		

Symbol (T _J = 25° C u	Test Conditions nless otherwise specified)		Ch Min.	_	istic Val Max.	
BV _{DSS}	$V_{GS} = 0 \text{ V}, I_{D} = 250 \mu\text{A}$		800			V
$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_{D} = 4 \text{ mA}$		3.0		5.0	V
GSS	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$				±100	nA
I _{DSS}	$V_{DS} = V_{DSS}$ $V_{GS} = 0 V$	T _J = 125° C			25 250	μA μA
R _{DS(on)}	$V_{GS} = 10 \text{ V}, I_{D} = I_{T_{L}} \text{ (Note 1)}$ Pulse test, t \le 300 \mus, duty cy	/cle d ≤ 2 %			650	mΩ



G = Gate D = Drain S = Source

Features

- Silicon chip on Direct-Copper-Bond substrate
 - High power dissipation
 - Isolated mounting surface
- 2500V electrical isolation
- Low drain to tab capacitance(<35pF)
- Low $R_{DS (on)} HDMOS^{TM}$ process
- Rugged polysilicon gate cell structure
- Unclamped Inductive Switching (UIS) rated
- Fast intrinsic Rectifier

Applications

- DC-DC converters
- Battery chargers
- Switched-mode and resonant-mode power supplies
- DC choppers
- AC motor control

Advantages

- Easy assembly: no screws, or isolation foils required
- Space savings
- High power density
- Low collector capacitance to ground (low EMI)

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Symbo					naracteristic Values otherwise specified)			
			Min.	Тур.	Max.			
g_{fs}		V_{DS} = 20 V; I_{D} = I_{T} , pulse test	9	16	S			
\mathbf{C}_{iss})			4600	pF			
Coss	}	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		330	pF			
C _{rss}	J			23	pF			
$\mathbf{t}_{d(on)}$)			27	ns			
t _r		$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, I_{D} = I$	Т	32	ns			
$\mathbf{t}_{d(off)}$		$R_{_{G}} = 5 \Omega (External)$		75	ns			
t _f)			29	ns			
$\mathbf{Q}_{g(on)}$)			71	nC			
\mathbf{Q}_{gs}	}	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, I_{D} = I_{T}$		21	nC			
\mathbf{Q}_{gd}	J			23	nC			
R _{thJC}					0.82 °C/W			
$\mathbf{R}_{\mathrm{thCS}}$				0.21	° C/W			

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Characteristic Values (T₁ = 25° C unless otherwise specified)

Symbol	Test Conditions Min.	Тур.	Max.	
Is	V _{GS} = 0 V		16	Α
I _{SM}	Repetitive		48	Α
V _{SD}	$I_F = I_S$, $V_{GS} = 0 \text{ V}$, Pulse test, t \leq 300 μ s, duty cycle d \leq 2 %		1.5	V
t _{rr}	$\begin{cases} I_F = 16 \text{ A, } -\text{di/dt} = 100 \text{ A/}\mu\text{s} \\ V_R = 100 \text{ V, } V_{GS} = 0 \text{ V} \end{cases}$	7	250	ns A
\mathbf{Q}_{RM})	8.0		μC

Note 1: Test Current $I_{\scriptscriptstyle T}$ = 8 A

ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated objective result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

ISOPLUS220™ (IXFC) Outline						
	33 b 30 b	2	X bt	5 5		
	ele	tom hea	tsink (Pir solated f			
-	INCH	ES	MTLLIM	1ETERS	1	
SYM	MIN	MAX	MIN	MAX		
Α	.157	.197	4.00	5.00		
A2	.098	.118	2.50	3.00		
h	025	051	0.00	1.20		

MYZ	INCH	FZ	MILLIMETERS		
2114	MIN	MAX	MIN	MAX	
Α	.157	.197	4.00	5.00	
A2	.098	.118	2.50	3.00	
Ь	.035	.051	0.90	1.30	
ь2	.049	.065	1,25	1.65	
ь4	.093	.100	2.35	2.55	
С	.028	.039	0.70	1.00	
D	.591	.630	15.00	16.00	
D1	.472	.512	12.00	13.00	
Ε	.394	.433	10.00	11.00	
E1	.295	.335	7.50	8.50	
е	.100	BASIC 2.55 BAS		BASIC	
L	.512	.571	13.00	14.50	
L1	.118	.138	3.0D	3.50	
Τ°			42.5°	47.5"	

Ref: IXYS CO 0177 R0